# BSS138LT1

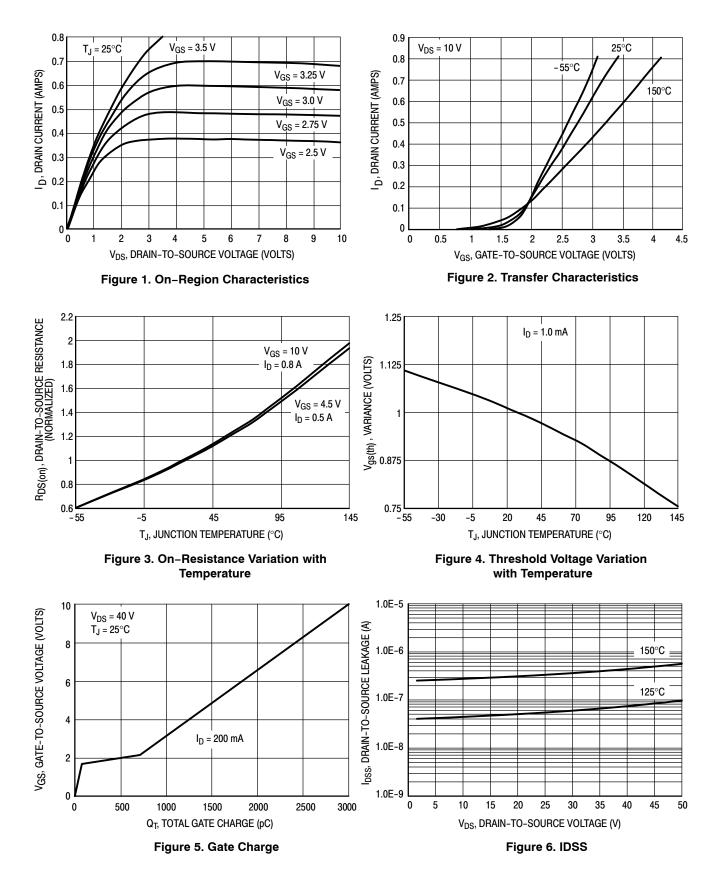
## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Char	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•		•	•	
Drain-to-Source Breakdown Voltage ( $V_{GS} = 0 \text{ Vdc}, I_D = 250 \mu \text{Adc}$ )			50	-	-	Vdc
$\label{eq:starsest} \begin{array}{l} \mbox{Zero Gate Voltage Drain Current} \\ (V_{DS} = 25 \mbox{ Vdc}, \mbox{ V}_{GS} = 0 \mbox{ Vdc}, \mbox{ 25 °C} \\ (V_{DS} = 50 \mbox{ Vdc}, \mbox{ V}_{GS} = 0 \mbox{ Vdc}, \mbox{ 25 °C} \\ (V_{DS} = 50 \mbox{ Vdc}, \mbox{ V}_{GS} = 0 \mbox{ Vdc}, \mbox{ 150 °C} \end{array}$	I <sub>DSS</sub>	- - -	- - -	0.1 0.5 5.0	μAdc	
Gate–Source Leakage Current (V <sub>GS</sub>	I <sub>GSS</sub>	-	-	±0.1	μAdc	
ON CHARACTERISTICS (Note 1)						
$ \begin{array}{l} \mbox{Gate-Source Threshold Voltage} \\ \mbox{(V}_{DS} = V_{GS}, \mbox{ I}_{D} = 1.0 \mbox{ mAdc}) \end{array} $	V <sub>GS(th)</sub>	0.5	-	1.5	Vdc	
$      Static Drain-to-Source On-Resistar \\ (V_{GS} = 2.75 \ Vdc, \ I_D < 200 \ mAdc, \ T_O(V_{GS} = 5.0 \ Vdc, \ I_D = 200 \ mAdc) $	r <sub>DS(on)</sub>		5.6 _	10 3.5	Ω	
Forward Transconductance (V <sub>DS</sub> = 25 Vdc, I <sub>D</sub> = 200 mAdc, f =	9 <sub>fs</sub>	100	-	-	mmhos	
OYNAMIC CHARACTERISTICS				•	•	
Input Capacitance	$(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1 \text{ MHz})$	C <sub>iss</sub>	-	40	50	pF
Output Capacitance	$(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1 \text{ MHz})$	C <sub>oss</sub>	-	12	25	
Transfer Capacitance	$(V_{DG} = 25 \text{ Vdc}, V_{GS} = 0, f = 1 \text{ MHz})$	C <sub>rss</sub>	-	3.5	5.0	
SWITCHING CHARACTERISTICS (No	ote 2)	•	•	•	•	•
Turn-On Delay Time		t <sub>d(on)</sub>	-	-	20	ns
Turn-Off Delay Time	$(V_{DD} = 30 \text{ Vdc}, I_D = 0.2 \text{ Adc},)$	t <sub>d (off)</sub>	_	_	20	1

Pulse rest. Pulse Width ≤ 500 μs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperature.

## BSS138LT1

### **TYPICAL ELECTRICAL CHARACTERISTICS**



## BSS138LT1

### **TYPICAL ELECTRICAL CHARACTERISTICS**

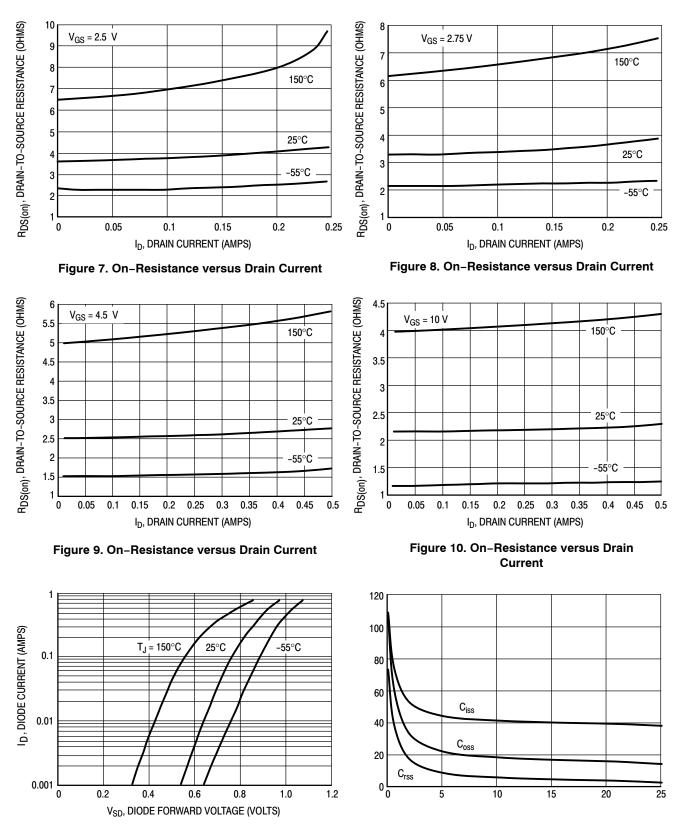
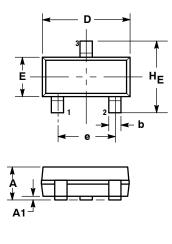


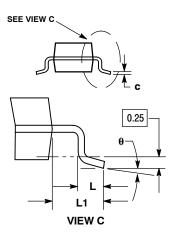
Figure 11. Body Diode Forward Voltage



#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

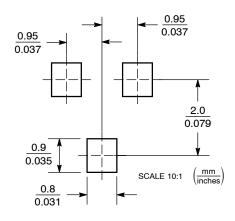
	М	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
с	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
Ш	1.20	1.30	1.40	0.047	0.051	0.055	
e	1.78	1.90	2.04	0.070	0.075	0.081	
L	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
HE	2.10	2.40	2.64	0.083	0.094	0.104	

STYLE 21:

PIN 1. GATE 2. SOURCE

3. DRAIN

### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and use registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other application is unich the failure of the SCILLC product costs of any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use payle copyright laws and is not for resale in any manner.

Phone: 421 33 790 2910

Phone: 81-3-5773-3850

Japan Customer Focus Center

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

BSS138LT1/D

Downloaded from Arrow.com.